

600 V, 75 A high speed trench field-stop IGBT with full rated silicon diode Rev. 1.0 — 3 July 2023

Preliminary data sheet

1. General description

The NGW75T60H3DF is a robust Insulated-Gate Bipolar Transistor (IGBT) featuring third-generation technology. It combines carrier stored trench-gate and field-stop (FS) structures. The NGW75T60H3DF is rated to 175 °C with optimized IGBT turn-off losses. This hard-switching 600 V, 75 A IGBT is optimized for high-voltage, high-frequency industrial power inverter applications.

2. Features and benefits

- Collector current (I_C) rated at 75 A
- Low conduction and switching losses
- Stable and tight parameters for easy parallel operation •
- Maximum junction temperature of 175 °C •
- Fully rated as a soft fast reverse recovery diode
- RoHS compliant, lead-free plating

3. Applications

- Power inverters
 - Uninterruptible Power Supply (UPS) inverter •
 - Photovoltaic (PV) strings
 - EV charging
- Induction heating
- Welding

4. Quick reference data

Table 1. Quick reference data						
Symbol	Parameter	Conditions	Min	Мах	Unit	
V _{CE}	collector-emitter voltage	T _j = 25 °C	-	600	V	
Tj	operating junction temperature		-40	+175	°C	



5. Pinning information

Table 2. F	Pinning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	mb	
2	С	collector		C I
3	E	emitter		
mb	С	mounting base; connected to collector		G C E aaa-036518

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
NGW75T60H3DF	TO-247-3L	Plastic single-ended through-hole package; heatsink mounted; 1 mounting hole; 3-lead TO-247-3L	<u>SOT429-2</u>		

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
IGBT	1		1		
V _{CE}	collector-emitter voltage	T _j = 25 °C	-	600	V
I _C	collector current	T _{case} = 25 °C [1]	-	80	A
		T _{case} = 100 °C [1]	-	80	A
I _{Cpuls}	peak pulse collector current [2]		-	300	A
V _{GE}	gate-emitter voltage		-20	+20	V
P _{tot}	total power dissipation	T _{case} = 25 °C	-	500	W
		T _{case} = 100 °C	-	250	W
Tj	operating junction temperature		-40	+175	°C
T _{stg}	storage temperature		-55	+150	°C
T _{solder}	soldering temperature		-	260	°C
М	mounting torque, M3 screw		-	0.6	Nm
Diode	1		1		
I _F	diode forward current	T _{case} = 25 °C [1]	-	80	A
		T _{case} = 100 °C [1]	-	80	A
I _{Fpuls}	peak pulse diode current [2]			300	A

[1] Value limited by bond wire and $T_{j(max)}$.

[2] t_p limited by $T_{j(max)}$.

8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-c)} thermal resistance from junction to case	IGBT	-	0.21	0.25	K/W	
	junction to case	diode	-	0.33	0.39	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	-	40	K/W

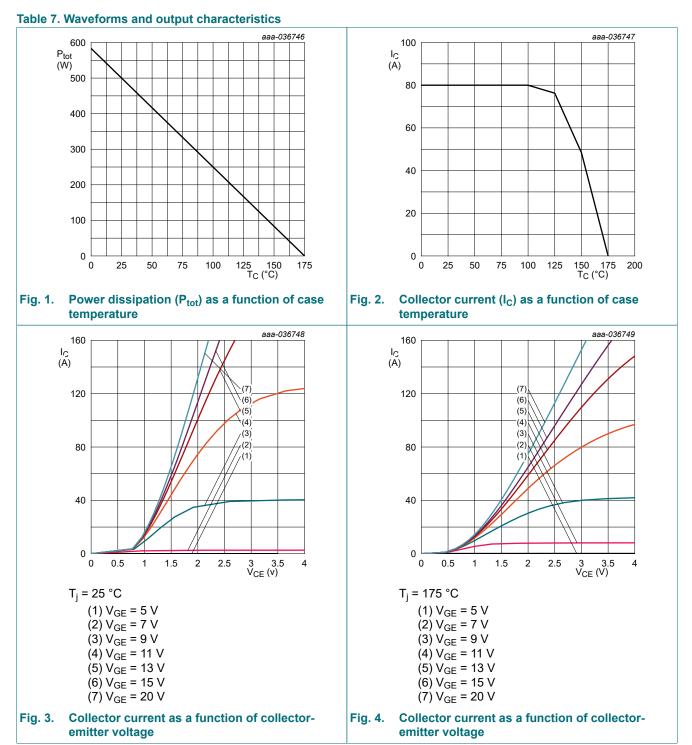
9. Characteristics

Table 6. Characteristics

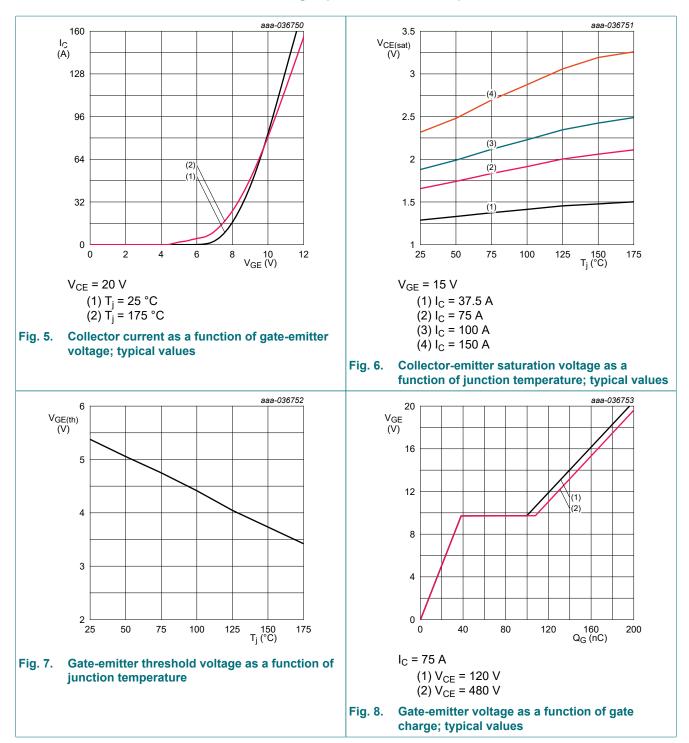
All values at T_i = 25 °C, unless otherwise specified.

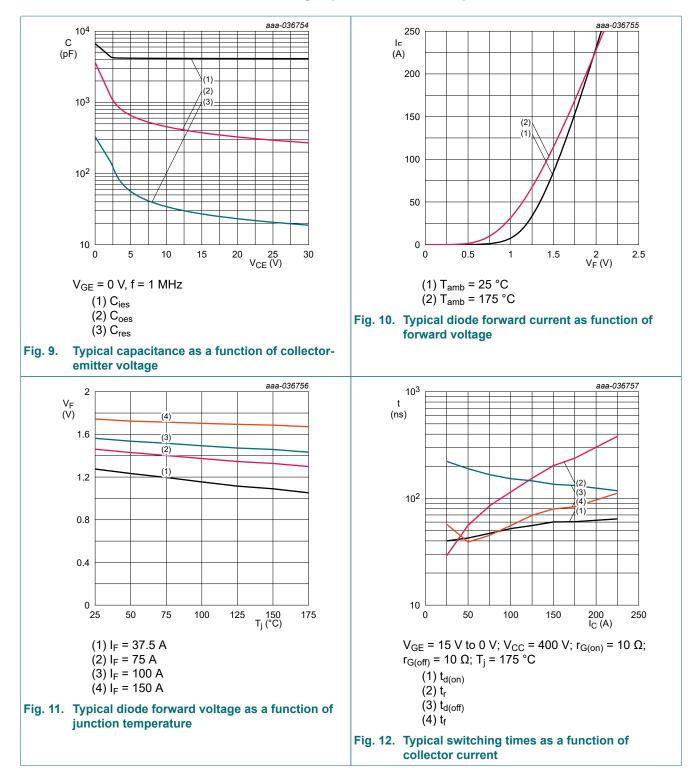
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics					
V _{(BR)CE}	collector-emitter breakdown voltage	V _{GE} = 0 V; I _C = 0.2 mA	600	-	-	V
V _{CEsat}	collector-emitter saturation	V _{GE} = 15 V; I _C = 75 A; T _j = 25 °C	-	1.67	2.2	V
voltage	voltage	V _{GE} = 15 V; I _C = 75 A; T _j = 175 °C	-	2.2	-	V
V _F diod	diode forward voltage	V _{GE} = 0 V; I _F = 75 A; T _j = 25 °C	-	1.5	2	V
		V _{GE} = 0 V; I _F = 75 A; T _j = 175 °C	-	1.3	-	V
V _{GE(th)}	gate-emitter threshold voltage	I_{C} = 0.75 mA; V_{CE} = V_{GE} ; T_{j} = 25 °C	4	5.5	7	V
I _{CES} zero gate voltage collector	V _{CE} = 600 V; V _{GE} = 0 V; T _j = 25 °C	-	-	400	μA	
	current	V _{CE} = 600 V; V _{GE} = 0 V; T _j = 175 °C	-	-	10	mA
I _{GES}	gate-emitter leakage current	V _{CE} = 0 V; V _{GE} = 20 V	-	-	200	nA
g fS	transconductance	V _{CE} = 20 V; I _C = 75 A; T _j = 25 °C	-	41	-	S
r _G	integrated gate resistor		-	0.8	-	Ω
Dynamic	c characteristics		I	1		
C _{ies}	input capacitance	V _{CE} = 25 V; V _{GE} = 0 V; f = 1 MHz	-	4200	-	pF
C _{oes}	output capacitance		-	265	-	pF
C _{res}	reverse transfer capacitance		-	19	-	pF
Q _G	gate charge	V_{CC} = 480 V; V_{GE} = 15 V; I_{C} = 75 A	-	160	-	nC
L _{sCE}	internal stray inductance	Measured 5 mm from case	-	7.9	-	nH

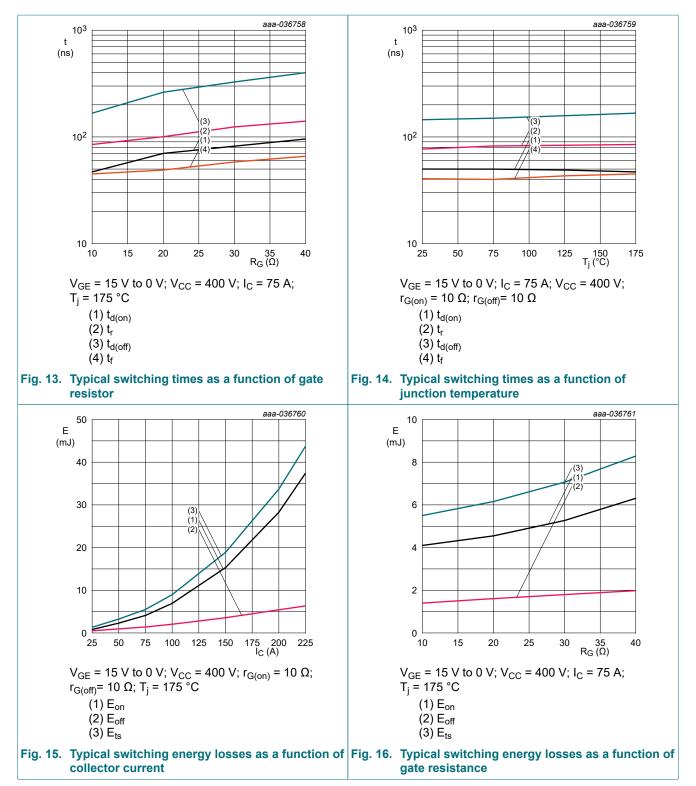
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
IGBT sw	vitching characteristics, indu	ctive load		_	1	1	
t _{d(on)}	turn-on delay time	V _{GE} = 15/0 V;	T _j = 25 °C	-	50	-	ns
		$V_{CC} = 400 \text{ V}; \text{ I}_{C} = 75 \text{ A};$ $r_{G(on)} = 10 \Omega; r_{G(off)} = 10 \Omega;$	T _j = 175 °C	-	47	-	ns
t _r	rise time	see Fig. 26 and Fig. 27	T _j = 25 °C	-	77	-	ns
			T _j = 175 °C	-	85	-	ns
t _{d(off)}	turn-off delay time		T _j = 25 °C	-	145	-	ns
			T _j = 175 °C	-	167	-	ns
t _f	fall time		T _j = 25 °C	-	40	-	ns
			T _j = 175 °C	-	45	-	ns
Eon	turn-on switching loss		T _j = 25 °C	-	3.6	-	mJ
			T _j = 175 °C	-	4.1	-	mJ
E _{off}	turn-off switching loss]	T _j = 25 °C	-	1.1	-	mJ
			T _j = 175 °C	-	1.4	-	mJ
E _{ts}	total switching loss		T _j = 25 °C	-	4.7	-	mJ
			T _j = 175 °C	-	5.5	-	mJ
Diode sv	witching characteristics, indu	ictive load	·				
t _{rr}	diode reverse recovery time	V _R = 400 V; I _F = 75 A;	T _j = 25 °C	-	203	-	ns
		ΔI _F /Δt = 500 A/μs; see <u>Fig. 25</u>	T _j = 175 °C	-	355	-	ns
Q _{rr}	diode reverse recovery	300 <u>rig. 20</u>	T _j = 25 °C	-	1790	-	nC
	charge		T _j = 175 °C	-	8000	-	nC
l _{rrm}	diode peak reverse recovery		T _j = 25 °C	-	22	-	А
	current		T _j = 175 °C	-	49	-	А
E _{rr}	reverse recovery energy		T _j = 25 °C	-	0.17	-	mJ
			T _j = 175 °C	-	1.0	-	mJ
di _{rr} /dt	diode peak rate or fall of		T _j = 25 °C	-	450	-	A/µs
	reverse recovery current		T _i = 175 °C	-	280	-	A/µs



9.1. Waveforms and output characteristics

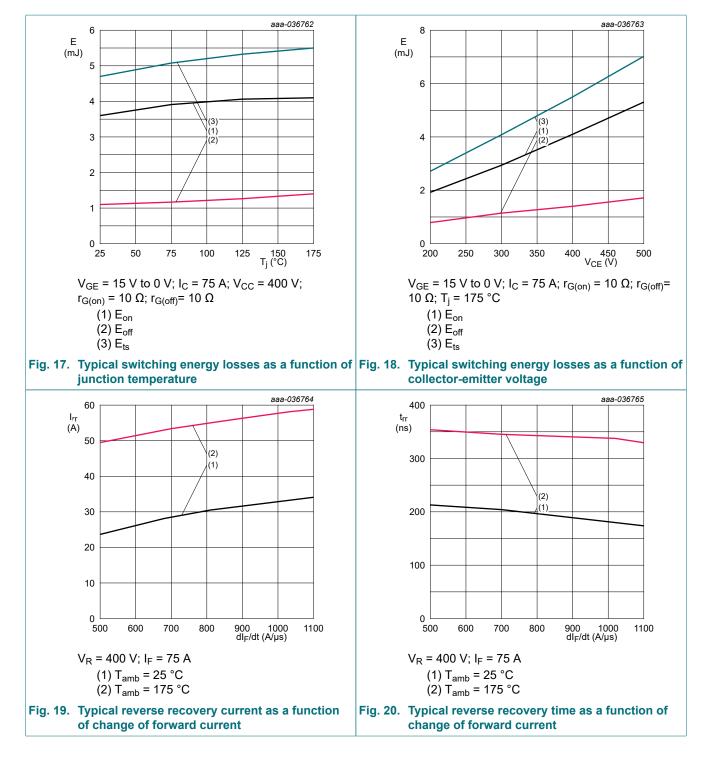




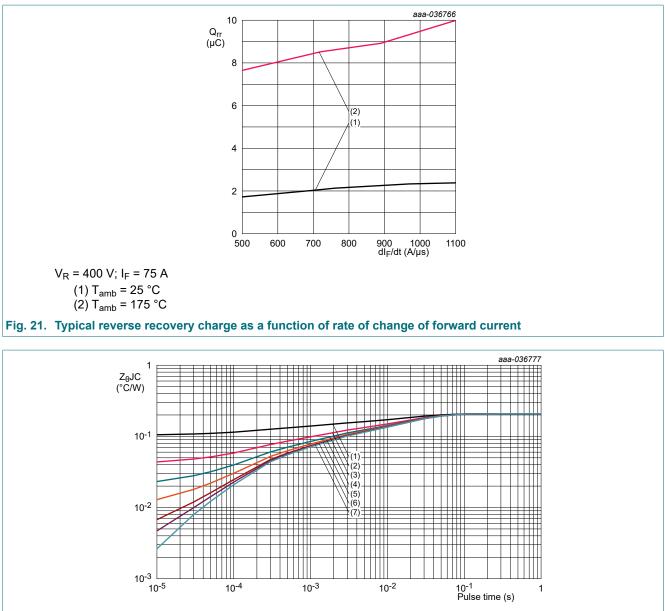


600 V, 75 A high speed trench field-stop IGBT with full rated silicon diode

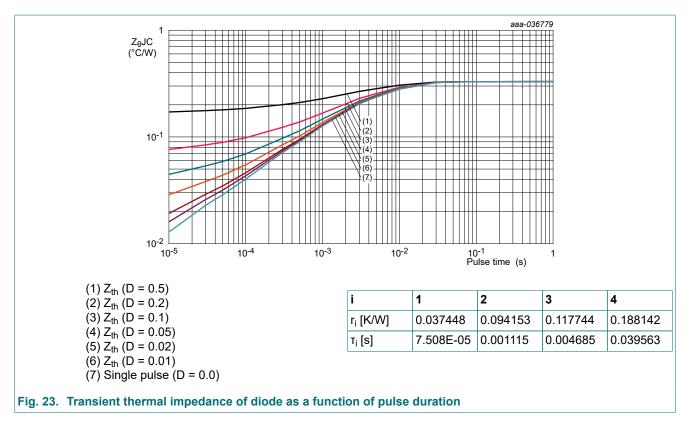
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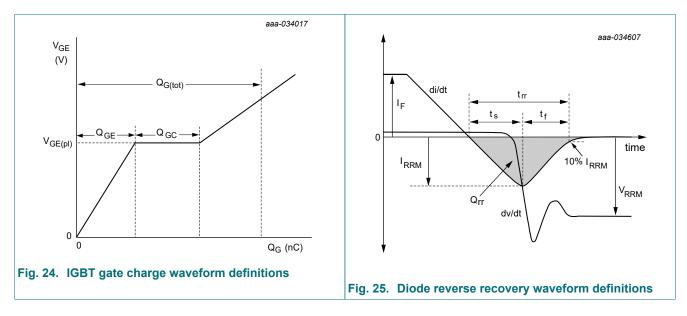
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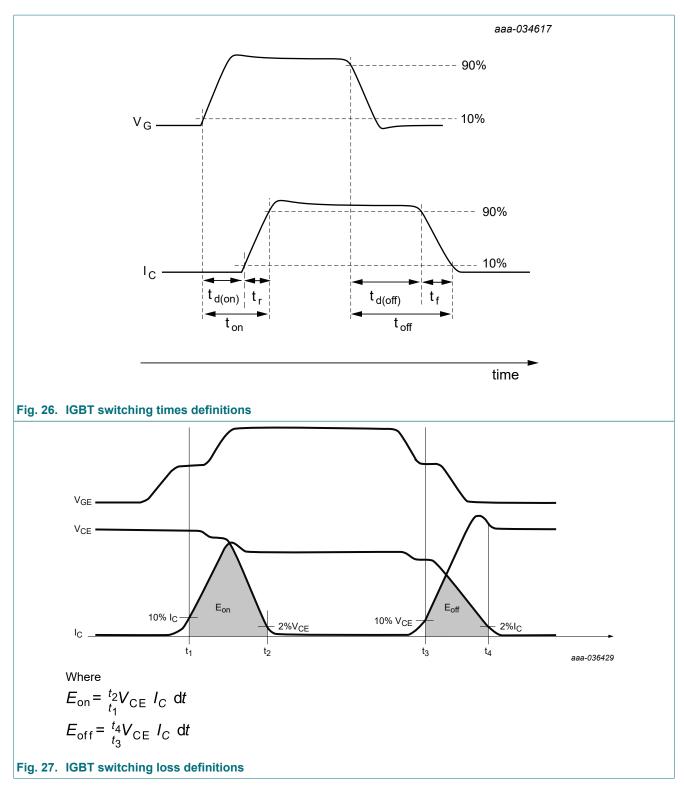
(1) Z _{th} (D = 0.5) (2) Z _{th} (D = 0.2)	i	1	2	3	4
(3) Z_{th} (D = 0.1)	r _i [K/W]	0.027464	0.045430	0.036075	0.099107
(4) Z_{th} (D = 0.05) (5) Z_{th} (D = 0.02)	т _і [S]	0.000138	0.000757	0.004623	0.279351
(6) Z _{th} (D = 0.01) (7) Single pulse (D = 0.0)					



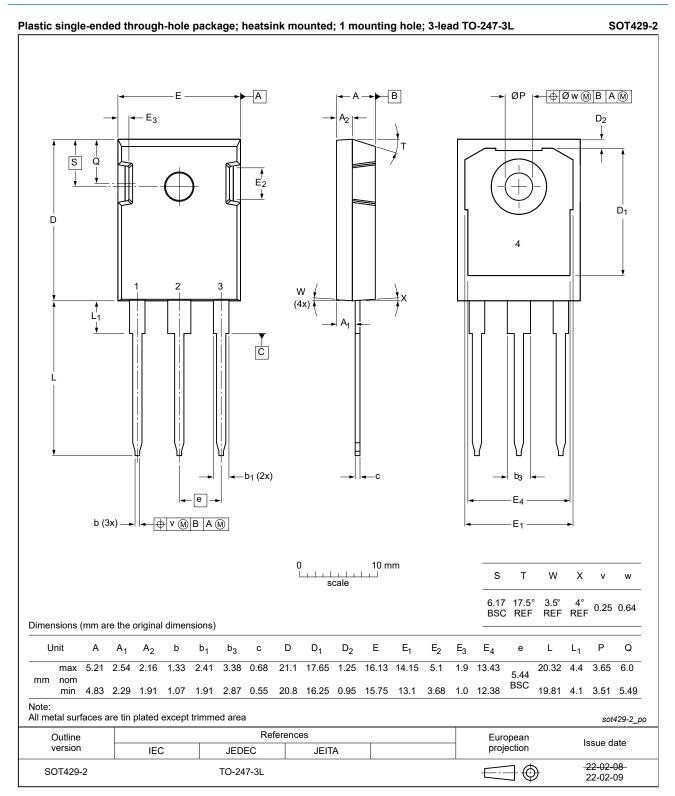
9.2. Waveforms



600 V, 75 A high speed trench field-stop IGBT with full rated silicon diode



10. Package outline





11. Revision history

Table 8. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
NGW75T60H3DF v. 1.0	20230703	Preliminary data sheet	-	-

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

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